IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:			
Tadashi IGUCHI et al.) Group Art Unit: 2826	
Application No.: 10/612,033) Examiner: Kevin V. QUINTO	
Filed:	July 3, 2003)
For:	SEMICONDUCTOR MEMORY PREVENTING AN ELECTRIC SI CIRCUIT BETWEEN A WORD L AND A SEMICONDUCTOR SUBSTRATE, AND MANUFACT METHOD FOR THE SEMICONDUCTOR MEMORY	INE)) Confirmation No.: 5852))
Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450			
Sir:			
PETITION FOR EXTENSION OF TIME			
Applicant petitions for a one month extension of time to file a reply to the Final			
Office Action of May 27, 2008. A fee of \$120.00 is enclosed.			
Please grant any additional extensions of time required to enter the attached			
reply and charge any additional required fees to Deposit Account 06-0916.			
	Respectfu		ully submitted,
			AN, HENDERSON, FARABOW, ARRETT & DUNNER, L.L.P.
Dated	: September 29, 2008	Jia Re	<u>a W. Lu</u> I W. Lu gg. No. 61,543 12) 408-4000